TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74HC374AP,TC74HC374AF

Octal D-Type Flip-Flop with 3-State Output

The TC74HC374A is a high speed CMOS OCTAL FLIP-FLOP with 3-STATE OUTPUT fabricated with silicon gate C^2MOS technology.

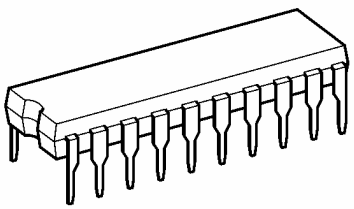
It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

These 8-bit D-type flip-flops are controlled by a clock input (CK) and an output enable input ($\overline{OE}$).

When the $\overline{OE}$ input is high, the eight outputs are in a high impedance state.

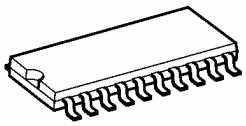
All inputs are equipped with protection circuits against static discharge or transient excess voltage.

TC74HC374AP



DIP20-P-300-2.54A

TC74HC374AF



SOP20-P-300-1.27A

Weight

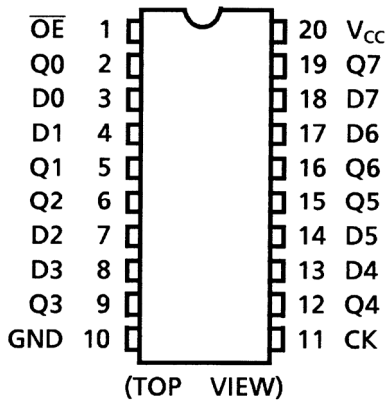
DIP20-P-300-2.54A : 1.30 g (typ.)

SOP20-P-300-1.27A : 0.22 g (typ.)

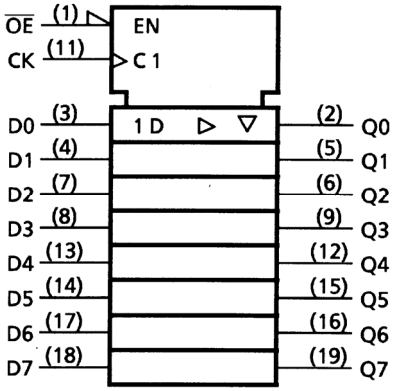
Features

- High speed: f_{max} = 77 MHz (typ.) at V_{CC} = 5 V
- Low power dissipation: I_{CC} = 4 μA (max) at Ta = 25°C
- High noise immunity: $V_{NIH} = V_{NIL}$ = 28% V_{CC} (min)
- Output drive capability: 15 LSTTL loads
- Symmetrical output impedance: $|I_{OH}| = I_{OL}$ = 6 mA (min)
- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range: V_{CC} (opr) = 2 to 6 V
- Pin and function compatible with 74LS374

Pin Assignment



IEC Logic Symbol



Truth Table

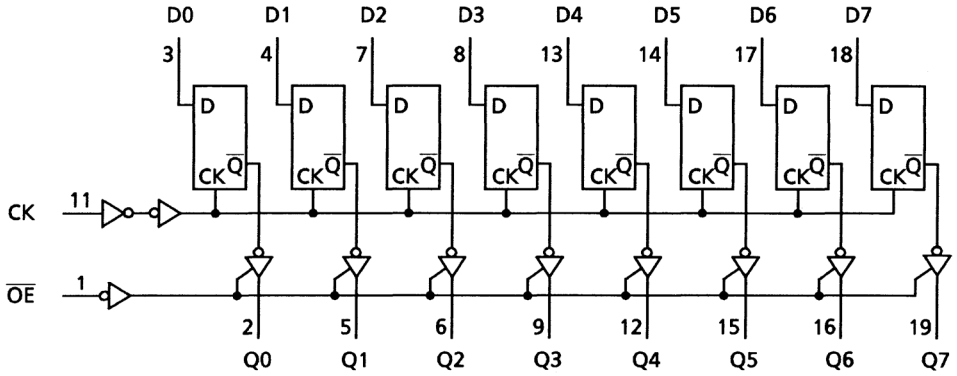
Inputs			Outputs
$\overline{OE}$	CK	D	Q
H	X	X	Z
L	↓	X	Q_n
L	↑	L	L
L	↑	H	H

X: Don't care

Z: High impedance

Q_n: No change

System Diagram



Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V_{CC}	−0.5 to 7	V
DC input voltage	V_{IN}	−0.5 to V_{CC} + 0.5	V
DC output voltage	V_{OUT}	−0.5 to V_{CC} + 0.5	V
Input diode current	I_{IK}	±20	mA
Output diode current	I_{OK}	±20	mA
DC output current	I_{OUT}	±35	mA
DC V_{CC}/ground current	I_{CC}	±75	mA
Power dissipation	P_D	500 (DIP) (Note 2)/180 (SOP)	mW
Storage temperature	T_{stg}	−65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.
Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook (“Handling Precautions”/“Derating Concept and Methods”) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: 500 mW in the range of Ta = −40 to 65°C. From Ta = 65 to 85°C a derating factor of −10 mW/°C shall be applied until 300 mW.

Operating Ranges (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V_{CC}	2 to 6	V
Input voltage	V_{IN}	0 to V_{CC}	V
Output voltage	V_{OUT}	0 to V_{CC}	V
Operating temperature	T_{opr}	−40 to 85	°C
Input rise and fall time	t_r, t_f	0 to 1000 (V_{CC} = 2.0 V) 0 to 500 (V_{CC} = 4.5 V) 0 to 400 (V_{CC} = 6.0 V)	ns

Note: The operating ranges must be maintained to ensure the normal operation of the device.
Unused inputs must be tied to either VCC or GND.

Electrical Characteristics

DC Characteristics

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = −40 to 85°C		Unit
			V_{CC} (V)	Min	Typ.	Max	Min	Max	
High-level input voltage	V_{IH}	—	2.0	1.50	—	—	1.50	—	V
			4.5	3.15	—	—	3.15	—	
			6.0	4.20	—	—	4.20	—	
Low-level input voltage	V_{IL}	—	2.0	—	—	0.50	—	0.50	V
			4.5	—	—	1.35	—	1.35	
			6.0	—	—	1.80	—	1.80	
High-level output voltage	V_{OH}	V_{IN} = V_{IH} or V_{IL}	2.0	1.9	2.0	—	1.9	—	V
		I_{OH} = −20 μA	4.5	4.4	4.5	—	4.4	—	
			6.0	5.9	6.0	—	5.9	—	
		I_{OH} = −6 mA	4.5	4.18	4.31	—	4.13	—	
		I_{OH} = −7.8 mA	6.0	5.68	5.80	—	5.63	—	
Low-level output voltage	V_{OL}	V_{IN} = V_{IH} or V_{IL}	2.0	—	0.0	0.1	—	0.1	V
		I_{OL} = 20 μA	4.5	—	0.0	0.1	—	0.1	
			6.0	—	0.0	0.1	—	0.1	
		I_{OL} = 6 mA	4.5	—	0.17	0.26	—	0.33	
		I_{OL} = 7.8 mA	6.0	—	0.18	0.26	—	0.33	
3-state output off-state current	I_{OZ}	V_{IN} = V_{IH} or V_{IL} V_{OUT} = V_{CC} or GND	6.0	—	—	±0.5	—	±5.0	μA
Input leakage current	I_{IN}	V_{IN} = V_{CC} or GND	6.0	—	—	±0.1	—	±1.0	μA
Quiescent supply current	I_{CC}	V_{IN} = V_{CC} or GND	6.0	—	—	4.0	—	40.0	μA

Timing Requirements (input: $t_r = t_f = 6$ ns)

Characteristics	Symbol	Test Condition	Ta = 25°C			Ta = −40 to 85°C	Unit
			V_{CC} (V)	Typ.	Limit	Limit	
Minimum pulse width (CK)	$t_{W(H)}$ $t_{W(L)}$	—	2.0	—	75	95	ns
			4.5	—	15	19	
			6.0	—	13	16	
Minimum set-up time (Dn)	t_s	—	2.0	—	75	95	ns
			4.5	—	15	19	
			6.0	—	13	16	
Minimum hold time (Dn)	t_h	—	2.0	—	0	0	ns
			4.5	—	0	0	
			6.0	—	0	0	
Clock frequency	f	—	2.0	—	6	5	MHz
			4.5	—	31	25	
			6.0	—	36	29	

AC Characteristics (input: $t_r = t_f = 6$ ns)

Characteristics	Symbol	Test Condition			Ta = 25°C			Ta = −40 to 85°C		Unit
			CL (pF)	V_{CC} (V)	Min	Typ.	Max	Min	Max	
Output transition time	t_{TLH} t_{THL}	—	50	2.0	—	20	60	—	75	ns
				4.5	—	6	12	—	15	
				6.0	—	5	10	—	13	
Propagation delay time (CK-Q)	t_{pLH} t_{pHL}	—	50	2.0	—	45	140	—	175	ns
				4.5	—	15	28	—	35	
				6.0	—	13	24	—	30	
			150	2.0	—	60	190	—	240	
				4.5	—	20	38	—	48	
				6.0	—	17	32	—	41	
Output enable time	t_{pZL} t_{pZH}	$R_L = 1$ kΩ	50	2.0	—	39	135	—	170	ns
				4.5	—	13	27	—	34	
				6.0	—	11	23	—	29	
			150	2.0	—	54	185	—	230	
				4.5	—	18	37	—	46	
				6.0	—	15	31	—	39	
Output enable time	t_{pLZ} t_{pHZ}	$R_L = 1$ kΩ	50	2.0	—	30	135	—	170	ns
				4.5	—	13	27	—	34	
				6.0	—	12	23	—	29	
Maximum clock frequency	f_{max}	—	50	2.0	6	18	—	5	—	MHz
				4.5	31	75	—	25	—	
				6.0	36	90	—	29	—	
Input capacitance	C_{IN}	—			—	5	10	—	10	pF
Output capacitance	C_{OUT}	—			—	10	—	—	—	pF
Power dissipation capacitance	C_{PD} (Note)	—			—	47	—	—	—	pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

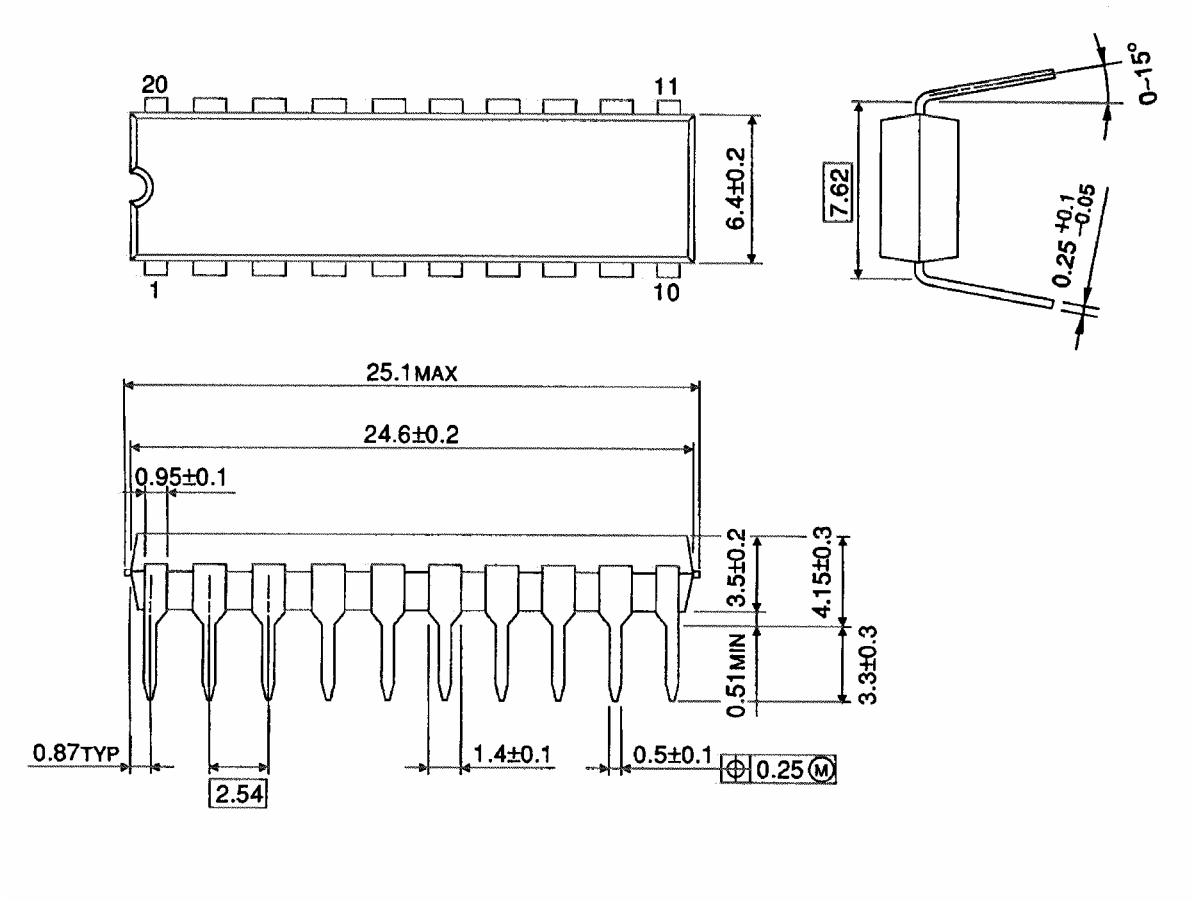
I_{CC} (opr) = $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8$ (per flip flop)

And the total C_{PD} when n pcs. of F/F operate can be gained by the following equation:

C_{PD} (total) = $30 + 17 \cdot n$

Package Dimensions

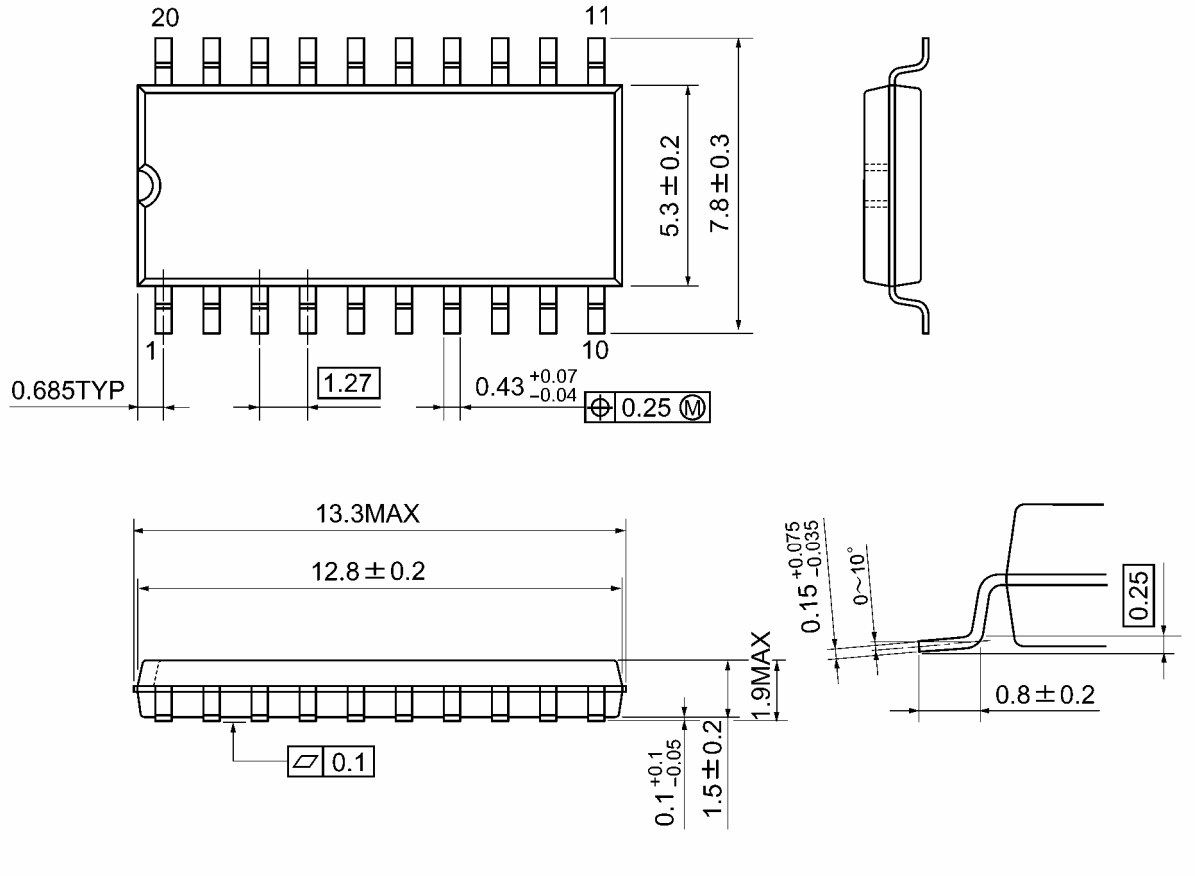
DIP20-P-300-2.54A Unit : mm



Weight: 1.30 g (typ.)

Package Dimensions

SOP20-P-300-1.27A Unit: mm



Weight: 0.22 g (typ.)

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20070701-EN GENERAL

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